



DATA SPECIFICATION FOR THE HIGH INTERCEPT LOW NOISE AMPLIFIER

MODEL NUMBER:

HILNA™ G2V1

40 dB GAIN

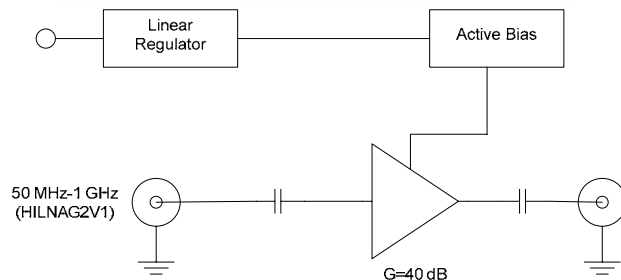
NuWaves Engineering

SUPERIOR ENGINEERING DESIGN SERVICES

NuWaves' HILNA™ G2V1 amplifiers are designed to achieve extremely low noise and high third-order intercept point along with extremely high gain. These characteristics are maintained across a wide band, from 50 MHz to 1 GHz.

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1. PRODUCT OVERVIEW

1.1 Product Highlights

- High Performance - Noise, Gain, Intercept, Dynamic Range: Unprecedented unique combination of extremely low noise (0.8 dB), High Gain (40 dB), High Output Intercept (+32 dBm), and wide band frequency coverage (50 MHz to 1 GHz).
- Robust Power Supply: Operates over a very broad range of power supply voltages (5-20 VDC), easily allowing the HILNA™ to be integrated into systems without regard to power supply precision. Included with each amplifier is a mating power connector with cable attached.
- Enclosure: The HILNA™ Amplifier is housed in a sleek black anodized extruded aluminum enclosure with optional mounting flanges.
- Completely Characterized: The HILNA™ family of amplifiers has been completely characterized over temperature, voltage, and frequency. The amplifiers are robust, offering significant value for the OEM user or the Systems Integrator.
- Low Cost: HILNA™ amplifiers are competitively priced. The unique combination of linearity, low noise, and broadband operation meet the demanding needs of state-of-the-art designs delivering high value for little cost.
- User Friendly: Reverse voltage protection and regulator thermal shutdown provide defenses against user interface issues.
- High Reliability: NuWaves' selections of conservatively rated components provide high reliability delivering high MTBF numbers. Each HILNA™ is quality inspected to IPC-A-610 Class III standards.

1.2 Product Description

Product	HILNA™
Functional Description	NuWaves' HILNA™ family of amplifiers is designed to achieve extremely low noise, high linearity, wideband operation while delivering high RF gain. Other characteristics include reverse voltage protection and an internal regulator and active bias.
Applications	IF or RF Buffer Amplifier ▪ Overcome Systematic RF Losses ▪ Increase Antenna Signal Levels ▪ Military Radios ▪ RF Wideband Front-Ends ▪ RF PreAmp ▪ TV ▪ Final Stage Amplifier for Low-Level Repeaters ▪ Long Cable Runs to Antenna ▪ Ultra Low Noise Applications ▪ LNA for Cellular Base Station ▪ High Linearity Systems ▪ General Purpose Amplification ▪ High Performance Receivers ▪ Amplification of Extremely Low-Level RF ▪ High Power Drive Signals for Increased Dynamic Range ▪ High Reliability RF Amplifier Applications ▪ Base Station Applications ▪ VHF/UHF Amplification ▪ Final PA for Low-Power Applications ▪ GPS LNA ▪ Low-Noise Transmit Driver ▪ Cable Modem ▪ Broadband Low Noise Gain Block ▪ Fixed Wireless ▪ Mobile Infrastructure
Users	Engineering and Scientific Laboratories ▪ Test and Measurement Facilities ▪ OEMs of RF High End Systems ▪ Research Laboratories ▪ Communications Engineering Firms ▪ Cable TV System Engineers ▪ RF System Integrators ▪ Test Ranges ▪ Universities ▪ Antenna Design Facilities ▪ Field Service Technicians ▪ Aerospace and Defense Systems ▪ Radio and TV Engineers ▪ Amateur Radio ▪ Scientific and Consulting Agencies ▪ Radio and Wireless Communication Services ▪ Precision Equipment Repair Organizations ▪ Professional and Technical Service Institutions
Mounting Technology	SMT

1.3 Product Variants

This data sheet focuses on the HILNA™ G2V1 variant; however, NuWaves offers several variants of the HILNA™ line-up. Furthermore, the HILNA™ family of amplifiers covers 50 MHz to 1.6 GHz, with plans to expand the HILNA™ line-up to 5 GHz. The variants and their availability include:

- G2V1 – 50 MHz to 1 GHz, 40 dB Gain (FULL PRODUCTION)
- V1 – 50 MHz to 1 GHz, 20 dB Gain (FULL PRODUCTION)
- GPS – 1.2 GHz to 1.6 GHz, 32 dB Gain (FULL PRODUCTION)



HILNA™ G2V1 Module Assembly
(shown with optional mounting flanges)

1.4 Part Number Ordering Information

Part Number	Description
HILNA™ G2V1	50MHz – 1GHz, 40 dB Gain, High Intercept Low Noise Amplifier, Extruded Aluminum Enclosure
HILNA™ V1	50MHz – 1GHz, 20 dB Gain, High Intercept Low Noise Amplifier, Extruded Aluminum Enclosure
HILNA™ GPS	1200 MHz – 1600 MHz, 32 dB Gain, High Intercept Low Noise Amplifier, Extruded Aluminum Enclosure

2. INSTALLATION, CONNECTING, AND USING THE HILNA™ AMPLIFIER

HILNA™ amplifiers have been designed to be highly reliable under the specified operating conditions. The following installation and hook-up guide lines should be followed to prevent damage to the RF module.

The HILNA™ G2V1 amplifier contains components that are sensitive to Electro-Static Discharge (ESD). The OEM variant should be installed in an ESD safe environment. The use of wrist strap, mats, and ground straps should be adhered to during the installation process.



CABLING: The HILNA™ G2V1 unit is equipped with high performance RF connectors. Gold plated SMA-type receptacles are used because they perform very well across the usable frequency range of the unit. For optimal performance, a high quality 50Ω coaxial cable with SMA-type plugs should be used to connect the unit to an antenna and also to the receiver. The best result will be obtained when the unit is installed as close as possible to the antenna.

CAUTION: Due to the wideband nature of the unit, installation should not be attempted on a tower with transmit antennas.

If cables with the SMA-type connectors are not available, high quality adaptors are available for most coaxial connector types.

POWER SUPPLY: The HILNA™ G2V1 contains internal linear voltage regulators. These regulators protect the circuitry from voltage variations at the input and allows for the wide operating voltage. The power connector is an industry standard 2.1mm circular connector. The only restrictions on the power source for the unit are:

- Capable of sourcing 200mA of current
- Capable of sourcing +5VDC to +20VDC

Car batteries (through a cigarette lighter adaptor), laboratory DC power supplies, or wall transformers are suitable power sources as long as the superimposed ripple is low in amplitude.

CONNECTIONS: Making the connection from the HILNA™ G2V1 to the receiver is easily accomplished. Note: Do not apply RF to the unit until after all cable connections are made and power has been applied.

One 50Ω coaxial cable is used to connect the antenna to the connector labeled "RF IN." A second 50Ω coaxial cable is used to connect the receiver input to the "RF OUT" connector on the unit. Finally, power is applied to the unit by first plugging the power cable sent with the unit into the 5-20VDC connector on the unit. Next connect the red lead to the + side of the power supply and connect the black lead to the – side of the power supply. Apply RF to the input cable assembly. Powering down the unit is done by reversing this procedure.

Connection Summary:

- Connect the RF Output to a good load. The characteristic impedance is 50Ω.
- Apply 5-20 VDC (12 VDC Typical) at the power connector.
- Connect an RF source to the RF Input connector.



Excess drive levels at the input to the amplifier can permanently damage the HILNA™ G2V1 amplifier. Under no circumstance should the RF Input level exceed -8 dBm.

ENVIRONMENT: The HILNA™ G2V1 unit is rated for operation from -20°C to +70°C. The enclosure is NOT watertight so the unit must be kept dry. It is recommended that the unit be installed in a well-ventilated area or mounted to a heat sink if the input voltage exceeds +15VDC. The unit will run warmer as the input voltage increases.

SUMMARY: The HILNA™ G2V1 is an easy way to increase the effective range of any receiver and/or is the perfect RF gain device for operating in the range of 50MHz to 1GHz. By following this installation guide, a unit can be successfully installed in most scenarios.

3. ELECTRICAL DATA

3.1 Absolute Maximum Ratings

Operating Voltage	20 V
RF P _{in}	-8 dBm
Operating Temperature	-20° C to + 70° C
Storage Temperature	-20° C to + 70° C

3.2 DC Characteristics

		min	typ	max
Operating Voltage	V	5	12	20
Current Consumption	mA	140	150	160

3.3 RF Characteristics

		HILNA™ G2V1		
		min	typ	max
Frequency Range	MHz	50		1000
Gain	dB	36	44	46
Noise Figure	dB	.6	.7	1.6
OIP3	dBm	29	30	32
P1dB	dBm	16	18	19
VSWR In		1.1	1.3	1.6
VSWR Out		1.1	1.5	2.3
Reverse Isolation	dB	50	53	56

Measurement Conditions:

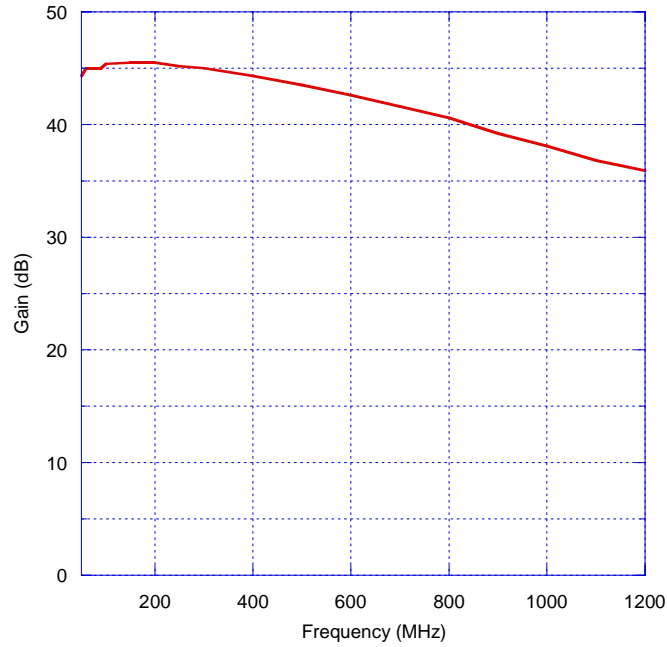
Z₀ = 50 Ω at input and output

P_{in} = -40 dBm

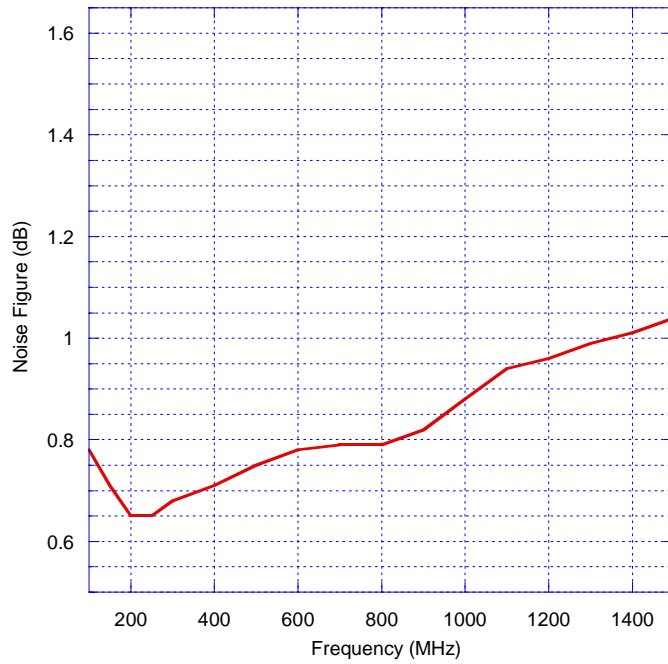
T_{amb} = 25° C

3.4 HILNA™ G2V1 Graphs

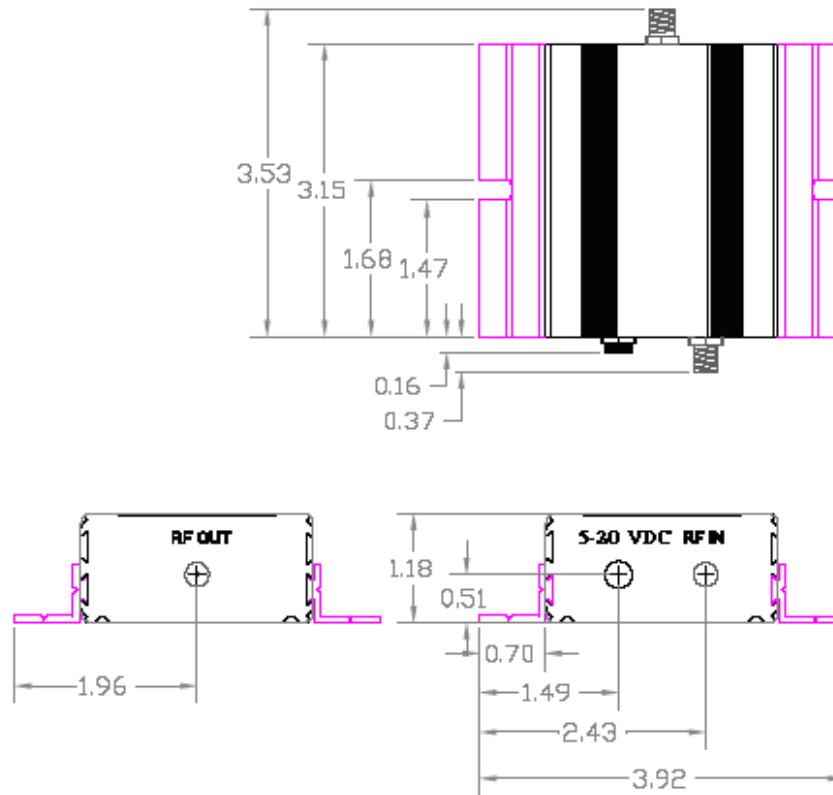
Gain vs. Frequency



Noise Figure vs. Frequency



4. MECHANICAL OUTLINE



RF Bulkhead Connector Type = SMA (Female)

RF Input and Output Mating Connector: SMA (Male)

DC Power Connector Type = 2.1mm Circular

Bulkhead Connector: Switchcraft 772A

Mating Connector: Switchcraft S760

Maximum Outline Dimensions (without mounting flanges)	
Length	3.15 in
Width	2.50 in
Height	1.18 in
Weight	4.2 oz.

5. GETTING ASSISTANCE – PRODUCT SUPPORT

NuWaves is proud of its products, and getting assistance in setting up your HILNA™ G2V1 amplifier is easy.

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NuWaves Home Page: www.nuwaves-ltd.com

Standard Product Warranty: http://nuwaves-ltd.com/pdf/Standard_Warranty.pdf

6. GENERAL INFORMATION

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